## NSN 5961-01-070-3590

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View Online at https://aerobasegroup.com/nsn/5961-01-070-3590 **Inclosure Material:** Metal **Overall Length:** 1.212 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-93 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.212 inches and 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 235.00 amperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0